PLT5 520

Metal Can® TO56

Green Laser Diode in TO56 Package

Applications

- Health Monitoring (Heart Rate Monitoring, Pulse Oximetry)
- Measurement Levelling
- Projection Home LED & Laser
- Projection Professional LED & Laser
- Stage Lighting (LED & Laser)

Features:

- Optical output power (continuous wave): 30 / 50 mW (T_C = 25°C)
- Typical emission wavelength: 520 nm
- Efficient radiation source for cw and pulsed operation
- Single tranverse mode semiconductor laser
- High modulation bandwidth
- TO56 package with photo diode

Ordering Information

Type	Peak output power typ. P_{opt}	Ordering Code
PLT5 520_B1-3	50 mW	Q65111A5771
PLT5 520_B1-6	30 mW	Q65111A6145

Maximum Ratings

T_C = 25 °C

Parameter	Symbol		Values
Operating temperature	T_{op}	min. max.	-20 °C 60 °C
Storage temperature	T_{stg}	min. max.	-40 °C 85 °C
Junction temperature	T_j	max.	150 °C
Forward current [1)]	I_F	max.	200 mA
Reverse voltage [2)]	V_R	max.	2 V
Soldering temperature t_{max} = 10 µs	T_S	max.	260 °C

Operation outside these conditions may damage the device. Operation at the maximum ratings influences lifetime.

Characteristics

P_{opt} = 50 mW (B1 - B3), P_{opt} = 30 mW (B4 - B6); T_{case} = 25 °C

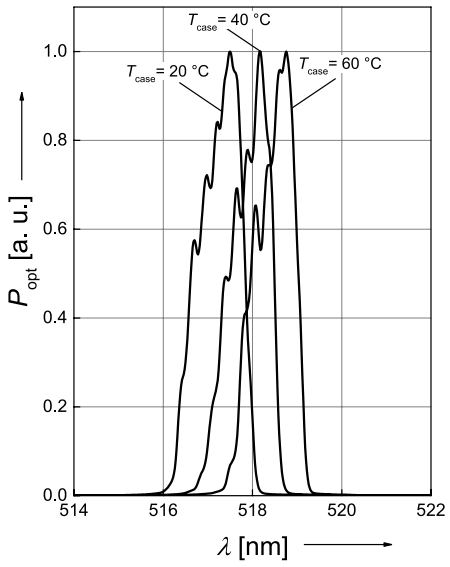
Parameter	Symbol		Values
Peak wavelength [3]	λ_{peak}	min. typ. max.	510 nm 520 nm 530 nm
Spectral bandwidth (FWHM)	$\Delta\lambda$	typ.	1 nm
Beam divergence (FWHM) parallel to pn-junction	$\Theta_{\parallel}$	min. typ. max.	5 ° 7 ° 9 °
Beam divergence (FWHM) perpendicular to pn-junction	$\Theta_{\perp}$	min. typ. max.	19 ° 22 ° 25 °
Threshold current B1 - B3	I_{th}	typ. max.	35 mA 55 mA
Threshold current B4 - B6	I_{th}	typ. max.	40 mA 55 mA
Forward voltage [4][5] B1 - B3	V_F	typ. max.	6.0 V 6.9 V
Forward current [1] B1 - B3	I_F	typ. max.	120 mA 140 mA
Forward current [1] B4 - B6	I_F	typ. max.	100 mA 140 mA
Forward voltage [4][5] B4 - B6	V_F	typ. max.	5.8 V 6.9 V
TE polarization	P_{TE}	typ.	100:1
Modulation frequency	f	min.	100 MHz
Monitor current [6][7]	I_m	typ.	90 µA
Thermal resistance junction case real	R_{thJC}	typ.	34 K / W

Wavelength Groups

Group	Peak wavelength [8] min. λ_{peak}	Peak wavelength [8] max. λ_{peak}
B1	510 nm	515 nm
B4	510 nm	515 nm
B2	515 nm	520 nm
B5	515 nm	520 nm
B3	520 nm	530 nm
B6	520 nm	530 nm

Relative Spectral Emission [9), 10)]

$P_{opt} = ƒ(\lambda)$; Group (B2; B5)



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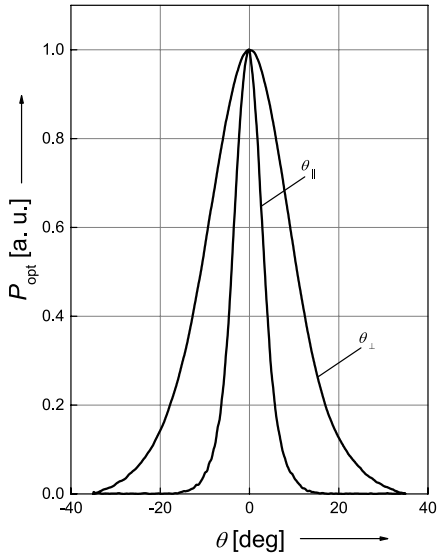
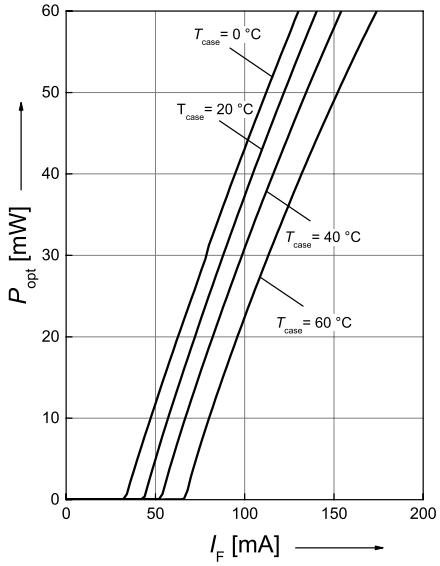
Beam Divergence 9), 10)

$P_{opt} = f(\Theta)$



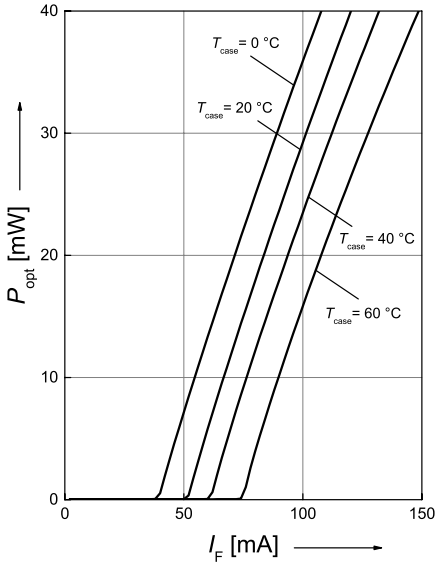
Optical Output Power 9), 10)

B1 - B3: $P_{opt} = f(I_F)$



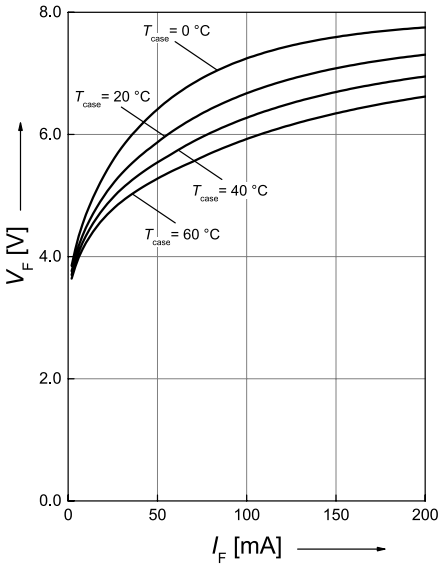
Optical Output Power 9), 10)

B4 - B6: $P_{opt} = f(I_F)$



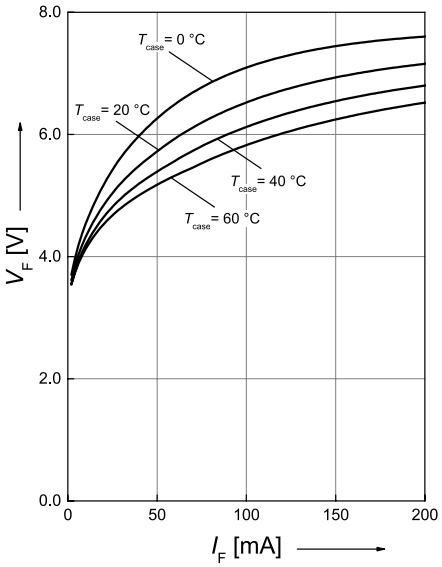
Opt. Power / Forward Voltage [9), 10)]

B1 - B3: $V_F = f(I_F)$



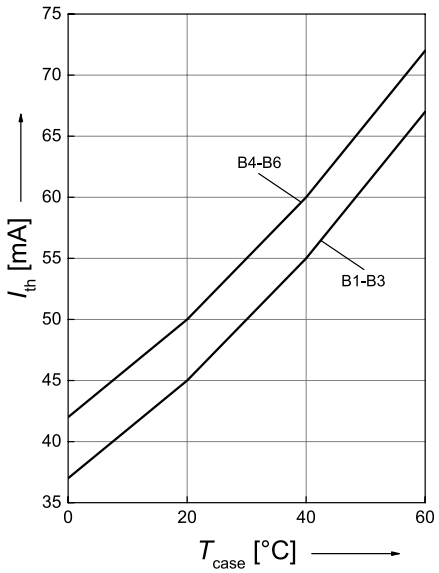
Opt. Power / Forward Voltage [9), 10)]

B4 - B6: $V_F = f(I_F)$



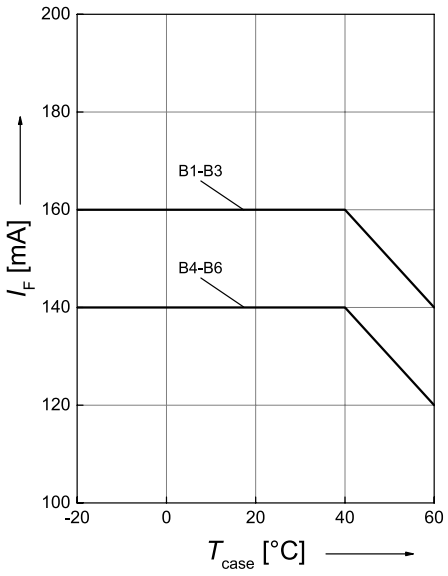
Threshold Current

$I_{th} = f(T_C)$

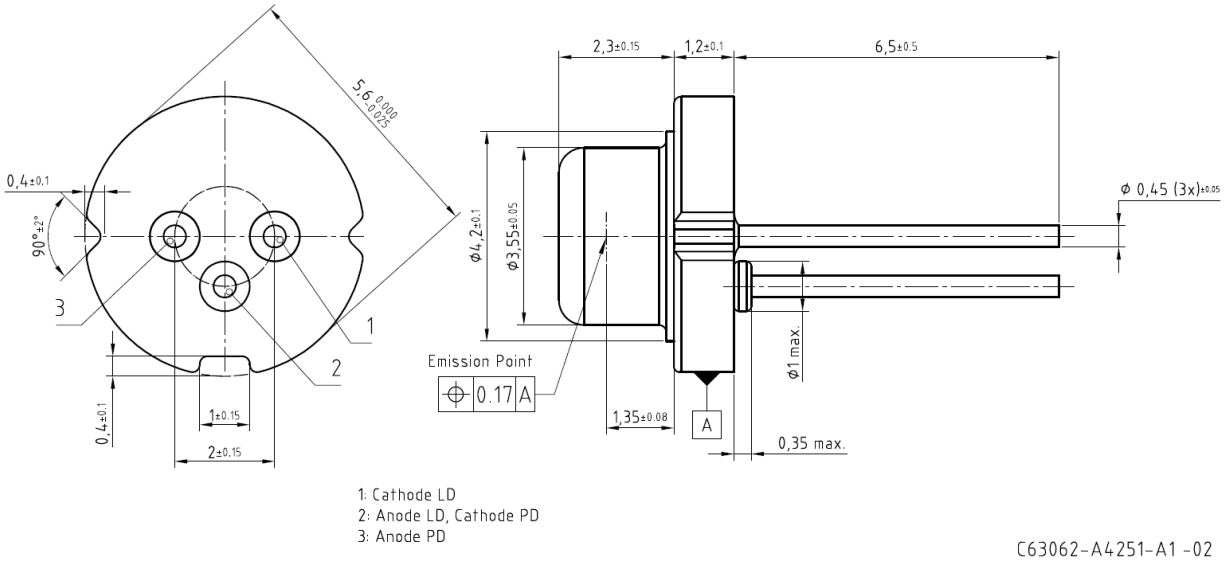


Max. Permissible Forward Current

$I_{F,max} = f(T_A)$;



Dimensional Drawing [11)]

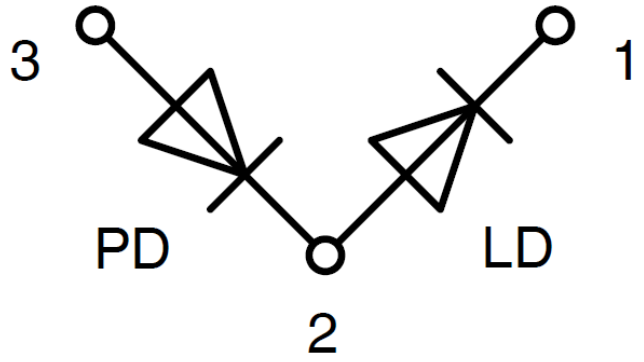


Further Information:

Approximate Weight: 310.0 mg

ESD advice: ATTENTION – Observe Precautions For Handling – Electrostatic Sensitive Device

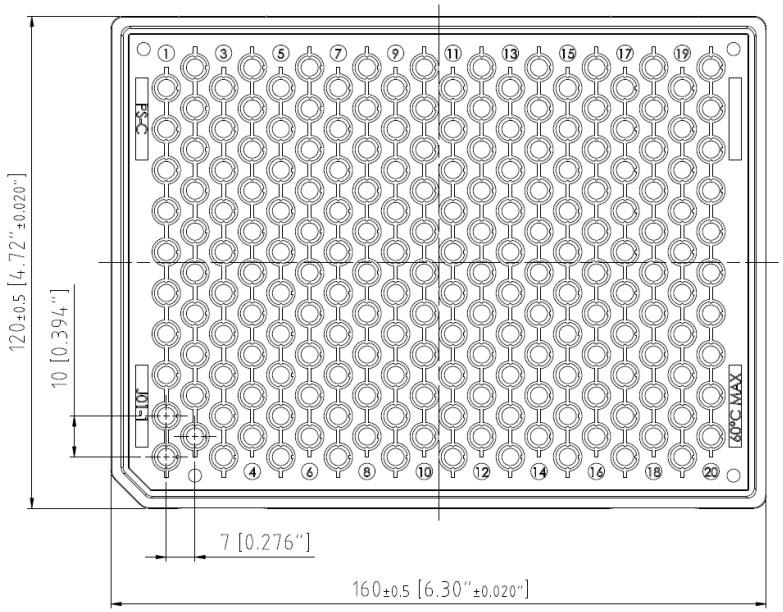
Electrical Internal Circuit



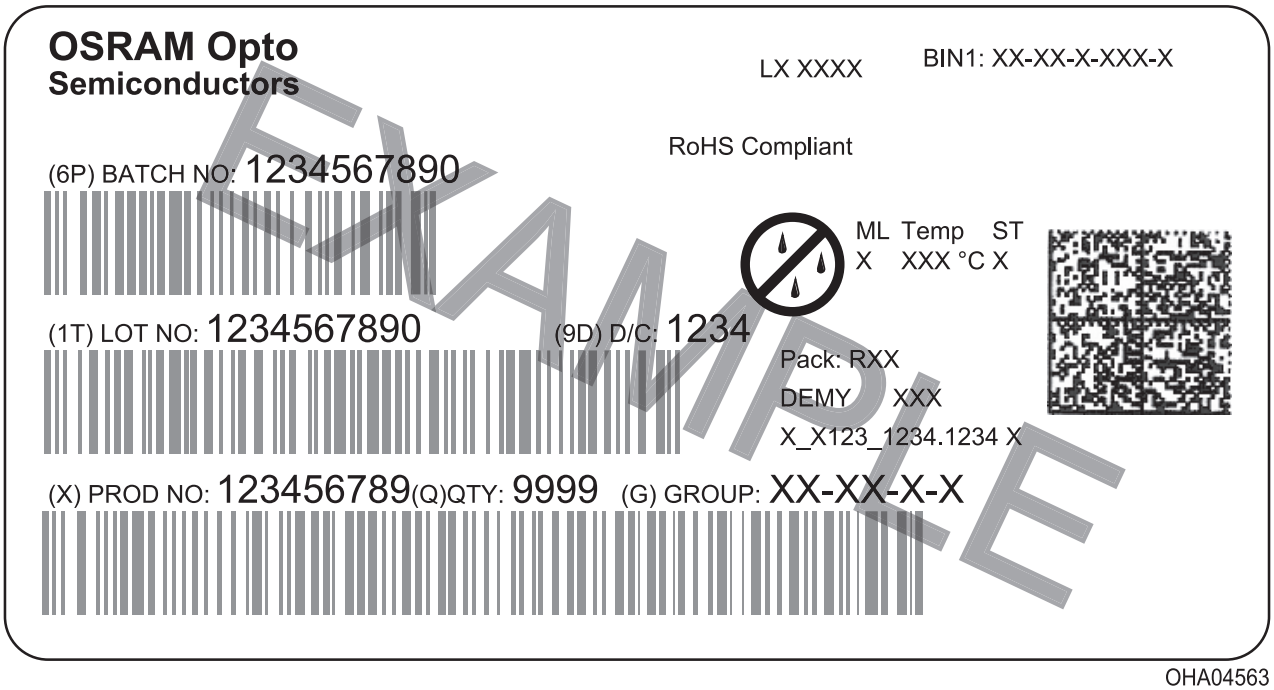
Pin	Description
PIN 1	LD Cathode
PIN 2	LD Anode, PD Cathode (case)
PIN 3	PD Anode

Tray [11)]

200 pieces per Tray



Barcode-Product-Label (BPL)



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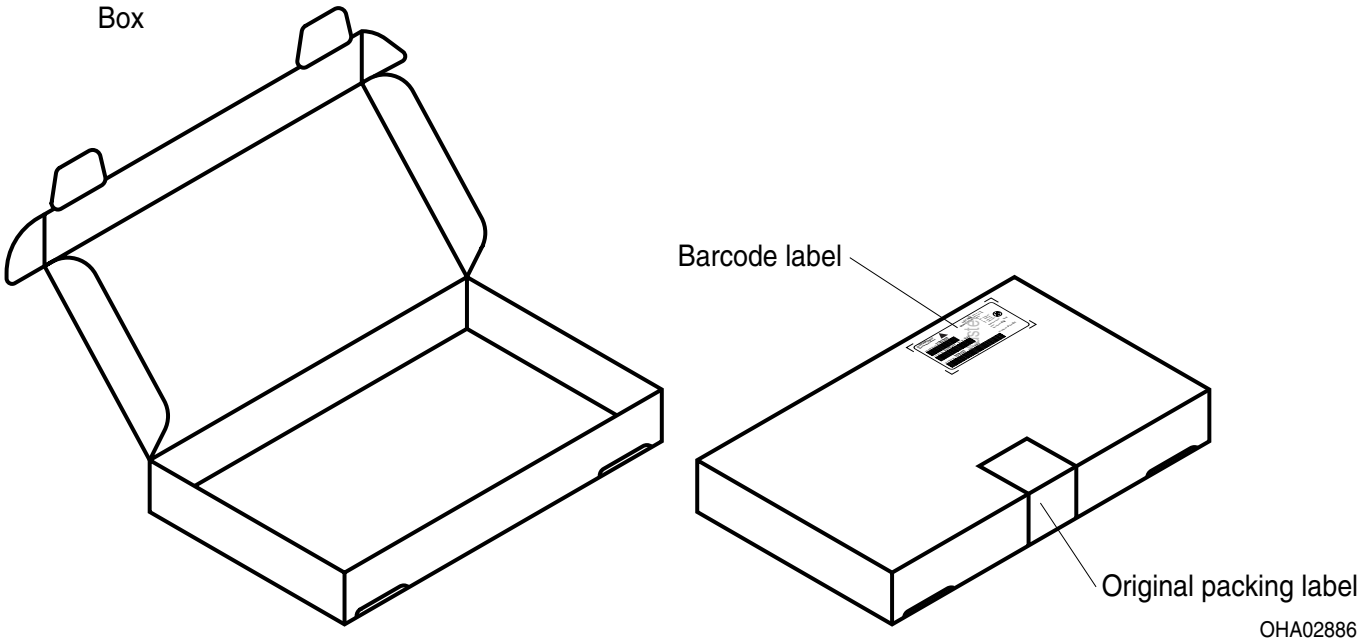
Schematic Transportation Box [11)]



Dimensions of Transportation Box

Width	Length	Height
215 ± 5 mm	265 ± 5 mm	95 ± 5 mm

Notes

Depending on the mode of operation, these devices emit highly concentrated visible and non visible light which can be hazardous to the human eye. Products which incorporate these devices have to follow the safety precautions given in IEC 60825-1.

Subcomponents of this device contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize device exposure to aggressive substances during storage, production, and use. Devices that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

Important notes of operation for laser diode

a) Electrical operation

OSRAMs laser diodes are designed for maximum performance and reliability. Operating the laser diode above the maximum rating even for very short periods of time can damage the laser diode or reduce its lifetime. The laser diode must be operated with a suitable power supply with minimized electrical noise. The laser diode is very sensitive to electrostatic discharge (ESD). Proper precautions must be taken.

b) Mounting instructions

In order to maintain the lifetime of the laser diode proper heat management is essential. Due to the design of the laser diode heat is dissipated only through the base plate of the diode‘s body. A proper heat conducting interconnection between the diodes base plate and the heat sink must be maintained.

For further application related information please visit www.osram-os.com/appnotes

Disclaimer

Attention please!
The information describes the type of component and shall not be considered as assured characteristics.
Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.
For information on the types in question please contact our Sales Organization.
If printed or downloaded, please find the latest version on the OSRAM OS website.

Packing
Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

Product and functional safety devices/applications or medical devices/applications
OSRAM OS components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.
OSRAM OS products are not qualified at module and system level for such application.

In case buyer – or customer supplied by buyer – considers using OSRAM OS components in product safety devices/applications or medical devices/applications, buyer and/or customer has to inform the local sales partner of OSRAM OS immediately and OSRAM OS and buyer and /or customer will analyze and coordinate the customer-specific request between OSRAM OS and buyer and/or customer.

Glossary

1) **Operating/Forward current:** IF is measured with an internal reproducibility of ±7 % (acc. to GUM with a coverage factor of k = 3).

2) **Reverse Operation:** Reverse Operation of 10 hours is permissible in total. Continuous reverse operation is not allowed.

3) **Wavelength:** λpeak is measured with an internal reproducibility of ±0.3 nm (acc. to GUM with a coverage factor of k = 3).

4) **Operating/Forward voltage:** VF is measured with an internal reproducibility of ±0.05 V (acc. to GUM with a coverage factor of k = 3).

5) **Forward Voltage:** The forward voltages are measured with a tolerance of ±0.1 V.

6) **Monitor current:** Monitor current refers to a reverse voltage of VRPD = 5 V. Monitor current is for short time power reference purpose only. Not guaranteed for accuracy.

7) **Monitor current:** For reference only.

8) **Wavelength:** The wavelengths are measured with a tolerance of ±1 nm.

9) **Typical Values:** Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.

10) **Testing temperature:** TA = 25°C (unless otherwise specified)

11) **Tolerance of Measure:** Unless otherwise noted in drawing, tolerances are specified with ±0.1 and dimensions are specified in mm.

Revision History

Version	Date	Change
1.1	2019-09-26	Description
1.2	2019-12-17	Characteristics

Published by OSRAM Opto Semiconductors GmbH
Leibnizstraße 4, D-93055 Regensburg

EU RoHS and China RoHS compliant product

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按照中国的相关法规和标准，不含有毒有害物质或元素。